## **Optoelectronics-I**

# Chapter-8

### Assoc. Prof. Dr. Isa NAVRUZ Lecture Notes - 2018

#### **Recommended books**





Department of Electrical and Electronics Enginnering, Ankara University Golbasi, ANKARA

# Refraction & Reflection-2

Objectives

When you finish this lesson you will be able to:

- ✓ Describe the Fresnel Equations
- ✓ Define Total Internal Reflection
- ✓ Explain the Fresnel coefficients in the Internal Reflection
- ✓ Explain the Fresnel coefficients in the External Reflection
- ✓ Describe the Brewster Angle

Reflection coefficient for s polarization

$$r_{s} = \frac{E_{r}}{E_{i}} = \frac{n_{i}cos\theta_{i} - n_{t}cos\theta_{t}}{n_{i}cos\theta_{i} + n_{t}cos\theta_{t}}$$

Transmission coefficient for s polarization

$$t_{s} = \frac{E_{t}}{E_{i}} = \frac{2n_{i}cos\theta_{i}}{n_{i}cos\theta_{i} + n_{t}cos\theta_{t}}$$

For the parallel polarization case, using similar methods, the result are

Reflection coefficient for p polarization

$$r_p = \frac{E_r}{E_i} = \frac{n_t \cos\theta_i - n_i \cos\theta_t}{n_t \cos\theta_i + n_i \cos\theta_t}$$

Transmission coefficient for p polarization

$$t_{p} = \frac{E_{t}}{E_{i}} = \frac{2n_{i}cos\theta_{i}}{n_{i}cos\theta_{t} + n_{t}cos\theta_{i}}$$

Using Snell's law, we can re-write:

$$r_{s} = r_{\perp} = -\frac{\sin(\theta_{i} - \theta_{i})}{\sin(\theta_{i} + \theta_{i})}$$

$$r_{p} = r_{\parallel} = +\frac{\tan(\theta_{i} - \theta_{i})}{\tan(\theta_{i} + \theta_{i})}$$

$$t_{s} = t_{\perp} = +\frac{2\sin\theta_{i}\cos\theta_{i}}{\sin(\theta_{i} + \theta_{i})}$$

$$t_{p} = t_{\parallel} = +\frac{2\sin\theta_{i}\cos\theta_{i}}{\sin(\theta_{i} + \theta_{i})}$$

### Reflectance (R) and Transmittance (T)



#### **Total Internal Reflection**

When  $n_i > n_t$ , the transmitted angle is bigger than incidence angle. In this case, if  $\theta t = 90^\circ$ , then the incidence angle is called the critical angle

$$\sin(\theta_c) = \frac{n_t}{n_i}$$

If  $\theta i > \theta c$ , Total Internal Reflection (TIR) occurs and an evanescent wave propagates along the boundary (i.e. high loss electric field propagating along the surface).



#### Internal Reflection (n1>n2)

This is case of traveling the light from a more dense medium into a less dense one



How much of the light is reflected ? How much of the light is transmitted? How about the phase of reflected and transmitted light?

Now let's calculate the reflection and transmission coefficients in both the s and p polarizations.

#### Internal Reflection (n1>n2)



#### Matlab Code

clear; clc; tetai=0:0.01:89.99; n1=1.5; n2=1; tetac=asind(n2/n1); tetat=asind(n1\*sind(0:0.01:tetac)/n2); plot(0:0.01:tetac,tetat); L=length(tetat); L2=length(tetai); tetat(L+1:1:L2)=90; rs=(n1\*cosd(tetai)-n2\*cosd(tetat))./(n1\*cosd(tetai)+n2\*cosd(tetat)); figure; plot(tetai,rs); hold on rp=(n2\*cosd(tetai)-n1\*cosd(tetat))./(n1\*cosd(tetat)+n2\*cosd(tetai)); plot(tetai,rp); ylim([-1-1]);  $\pi$ 



External Reflection (n1<n2)



If r is real and r > 0 then there are no phase changes after reflection.

If r < 0 then there are  $\pi$  (180°) phase changes after reflection.



**For "p" case**,  $\pi$  phase shift for  $\theta < \theta_B$ No phase shift for  $\theta > \theta_B$ 

5

0

-1

0

20

Brewster's Angle ( $\theta_{B}$ ) :

Note that  $r_p$  is zero at a certain angle. This angle only occurs when the p-polarized (TM mode) light is reflected in both the internal and external reflection cases.

Brewster's angle equals to 56.3° for  $n_i = 1$  and  $n_t = 1.5$ values.  $r_p = r_{\parallel} = \frac{\tan(\theta_i - \theta_t)}{\tan(\theta_i + \theta_t)} = 0$ 

$$\theta_{i} + \theta_{t} = \frac{\pi}{2}$$
  
 $n_{i} \sin \theta_{i} = n_{t} \sin \left(\frac{\pi}{2} - \theta_{i}\right) = n_{t} \cos \theta$ 

11



40

 $\theta_{\mathbf{R}}$ 

60

80

Brewter's angle is the angle that satisfies this equation,

$$\theta_{\rm B} = \tan^{-1} \frac{n_{\rm t}}{n_{\rm i}}$$

Brewster's angle (or, polarizing angle) (No reflection of TM mode)

Brewster's Angle ( $\theta_{\rm B}$ ) :

#### Example:

Show that polarizing (Brewter's) angles for internal and external reflection between the same two media must be complementary of  $\pi/2$ 

For external reflection 
$$\implies \theta_B$$
  
For internal reflection  $\implies \theta'_B$   $\theta'_B = \pi/2$ 

Example:

For an air-glass interface ( $n_i = 1$  and  $n_t = 1.5$ ), suppose that the incident light is perpendicularly (S) polarized Light. When  $\theta_i = 0$ ,

a) Calculate the reflection and transmission coefficients (r, t)

b) Calculate the reflectance (R) and Transmittance (T)

c) Explain the phase change of reflected light and transmitted light.

Example:

Show analytically that  $R_p + T_p = 1$ , where  $R_p$  and  $T_p$  is given by

$$r_p = \frac{E_r}{E_i} = \frac{n_t \cos\theta_i - n_i \cos\theta_t}{n_t \cos\theta_i + n_i \cos\theta_t}$$

$$t_{p} = \frac{E_{t}}{E_{i}} = \frac{2n_{i}cos\theta_{i}}{n_{i}cos\theta_{t} + n_{t}cos\theta_{i}}$$

#### Example:

a)Consider three dielectric media with flat and parallel boundaries with refractive indices n1, n2, and n3. Show that for normal incidence the reflection coefficient between layers 1 and 2 is the same as that between layers 2 and 3 if n2 = n1 n3. What is the significance of this?

b)Consider a Si photodiode that is designed for operation at 900 nm. Given a choice of two possible antireflection coatings, SiO2 with a refractive index of 1.5 and TiO2 with a refractive index of 2.3 which would you use and what would be the thickness of the antireflection coating you chose? The refractive index of Si is 3.5.

Example:

Consider that light propagates at normal incidence from air,  $n_1 = 1$ , to semiconductor likes a photocell with a refractive index of  $n_3=3.5$  as given in Fig-a



- a) What is the reflection coefficient (r) and the reflectance (R) with respect to the incident beam?
- b) When the semiconductor material is coated with thin layer of electric material such as  $Si_3N_4$  (silicon nitride) that has an intermediate refractive index of  $n_2=1.9$  as given in Fig-(b), the loss can be reduced. In this case, calculate the reflection coefficient (r) and the reflectance (R) and discuss the loss.
- c) In this system, how can you explain the phase matching relation to thickness of antireflective layer?

Example:

A ray of light which is traveling in a glass medium of refractive index n1 = 1.450 becomes incident on a less dense glass medium of refractive index n2 = 1.430. Suppose that the free space wavelength ( $\lambda$ ) of the light ray is 1 µm. a.

a)What should be the minimum incidence angle for TIR?

b) What is the phase change in the reflected wave when  $\theta i = 85^{\circ}$  and when  $\theta i = 90^{\circ}$ ? c.